To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR
2SK3053

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

DESCRIPTION

The 2SK3053 is N-Channel MOS Field Effect Transistor designed for high current switching applications in consumer instruments.

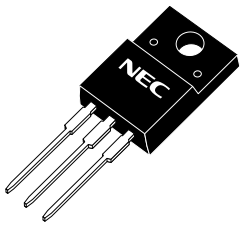
ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3053	Isolated TO-220

FEATURES

- Low On-State Resistance
  $R_{DS(on)1}$ = 45 mΩ MAX. (V_{GS} = 10 V, I_D = 13 A)
  $R_{DS(on)2}$ = 70 mΩ MAX. (V_{GS} = 4.0 V, I_D = 13 A)
- Low C_{iss} : C_{iss} = 790 pF TYP.
- Built-in Gate Protection Diode
- Isolated TO-220 package

(Isolated TO-220)



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C)

Drain to Source Voltage	V_{DSS}	60	V
Gate to Source Voltage	$V_{GSS(AC)}$	±20	V
Gate to Source Voltage	$V_{GSS(DC)}$	+20, –10	V
Drain Current (DC)	$I_{D(DC)}$	±25	A
Drain Current (Pulse) Note1	$I_{D(pulse)}$	±75	A
Total Power Dissipation (T_C = 25°C)	P_T	30	W
Total Power Dissipation (T_A = 25°C)	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C
Single Avalanche Current Note2	I_{AS}	12.5	A
Single Avalanche Energy Note2	E_{AS}	15.6	mJ

Notes 1. PW ≤ 10 μs, Duty cycle ≤ 1 %

★ **2.** Starting T_{ch} = 25 °C, V_{DD} = 30 V, R_G = 25 Ω, V_{GS} = 20 V → 0 V

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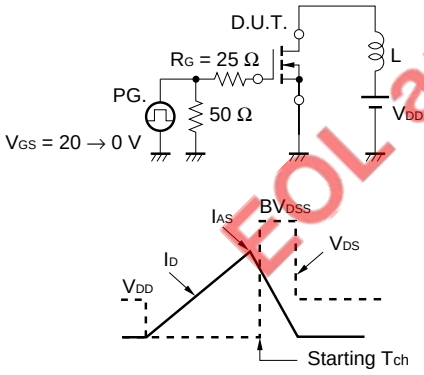
Printed in Japan

The mark ★ shows major revised points.

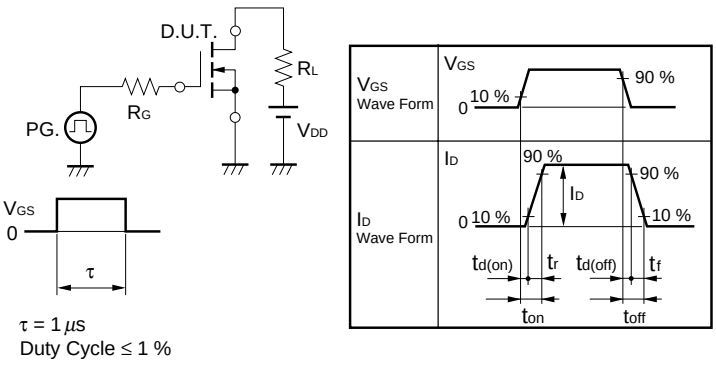
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = 10 V, I_D = 13 A		28	45	mΩ
	$R_{DS(on)2}$	V_{GS} = 4.0 V, I_D = 13 A		46	70	mΩ
Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	1.0	1.6	2.0	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 13 A	8.0	16		S
Drain Leakage Current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V			10	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Input Capacitance	C_{iss}	V_{DS} = 10 V		790		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		240		pF
Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		100		pF
Turn-on Delay Time	$t_{d(on)}$	I_D = 13 A		20		ns
★ Rise Time	t_r	V_{GS} = 10 V		200		ns
Turn-off Delay Time	$t_{d(off)}$	V_{DD} = 30 V		65		ns
Fall Time	t_f	R_G = 10 Ω		95		ns
Total Gate Charge	Q_G	I_D = 25 A		20		nC
Gate to Source Charge	Q_{GS}	V_{DD} = 48 V		3.0		nC
★ Gate to Drain Charge	Q_{GD}	V_{GS} = 10 V		6.5		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 25 A, V_{GS} = 0 V		1.0		V
Reverse Recovery Time	t_{rr}	I_F = 25 A, V_{GS} = 0 V		40		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		45		nC

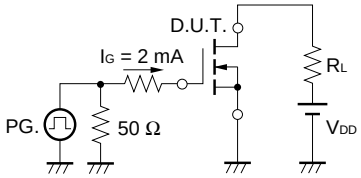
TEST CIRCUIT 1 AVALANCHE CAPABILITY



★ TEST CIRCUIT 2 SWITCHING TIME

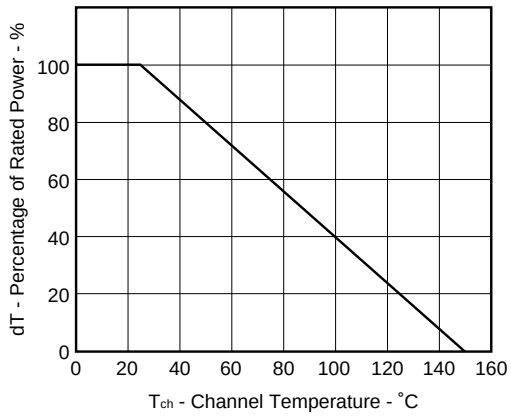


TEST CIRCUIT 3 GATE CHARGE

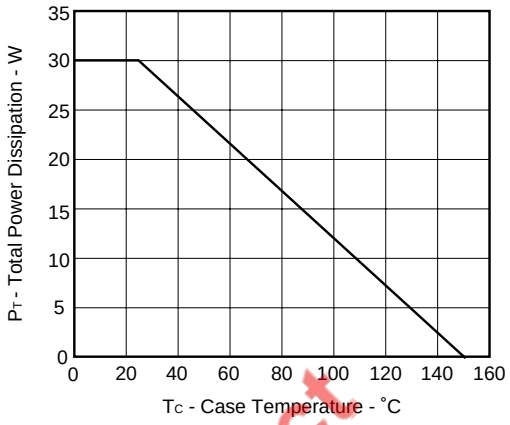


TYPICAL CHARACTERISTICS (T_A = 25 °C)

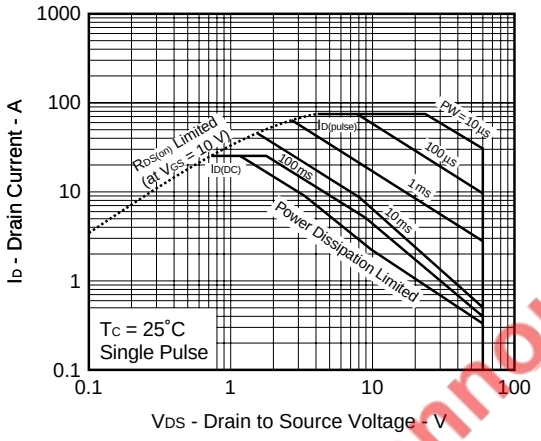
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



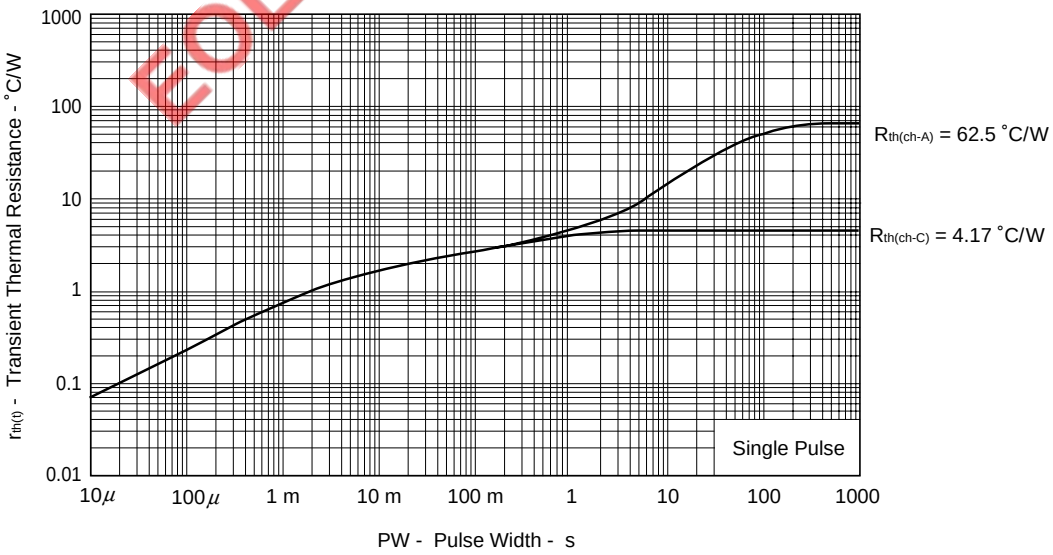
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



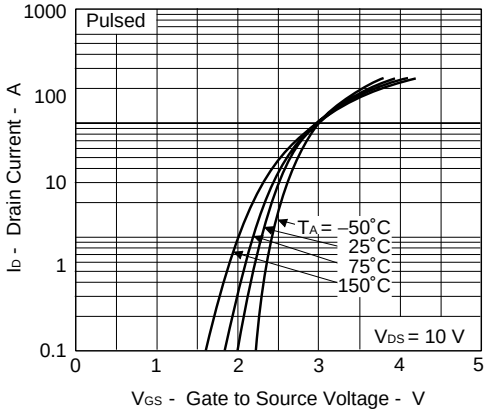
★ FORWARD BIAS SAFE OPERATING AREA



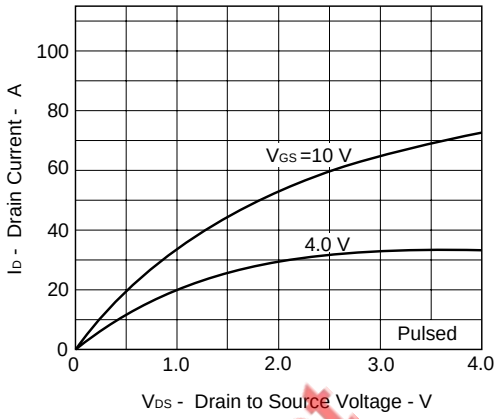
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



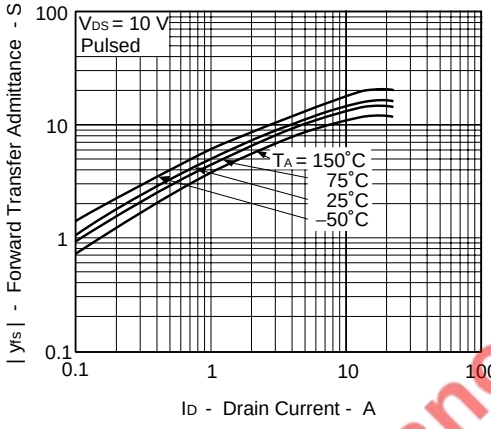
FORWARD TRANSFER CHARACTERISTICS



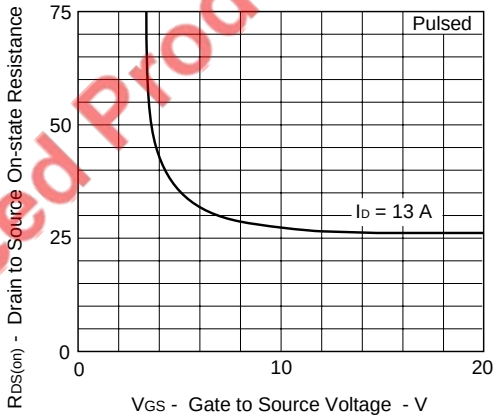
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



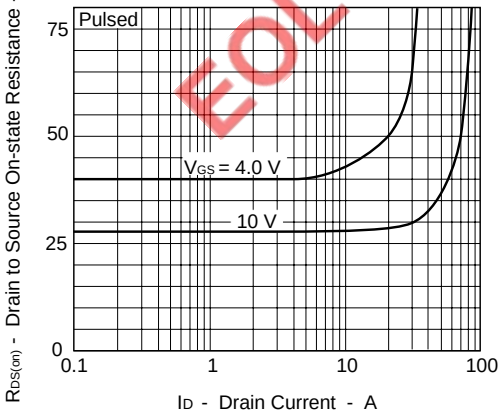
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



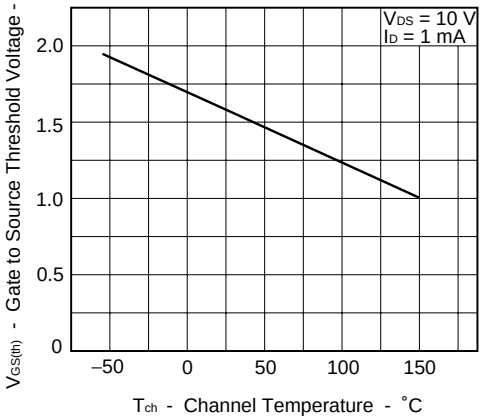
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



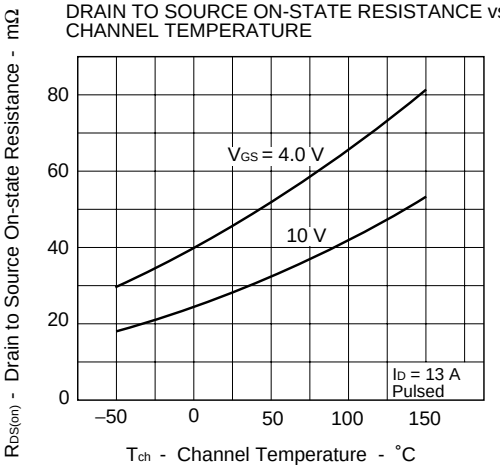
DRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENT



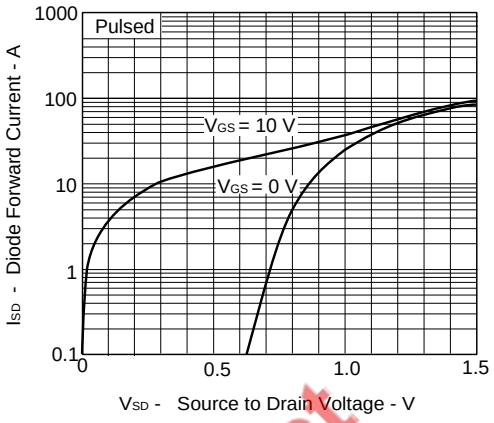
GATE TO SOURCE THRESHOLD VOLTAGE vs.
CHANNEL TEMPERATURE



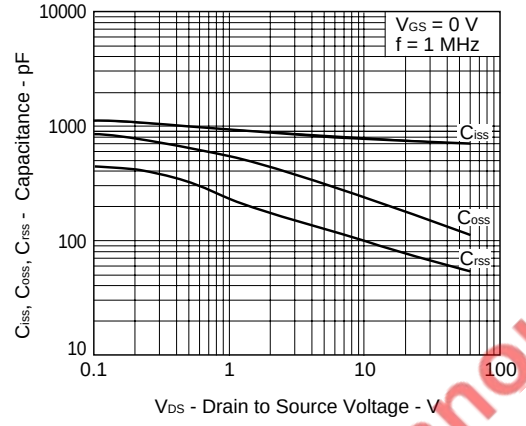
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



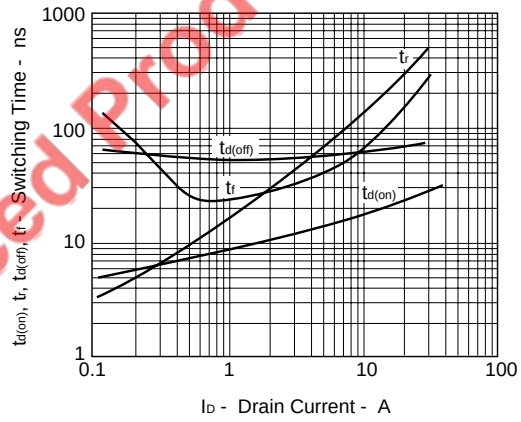
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



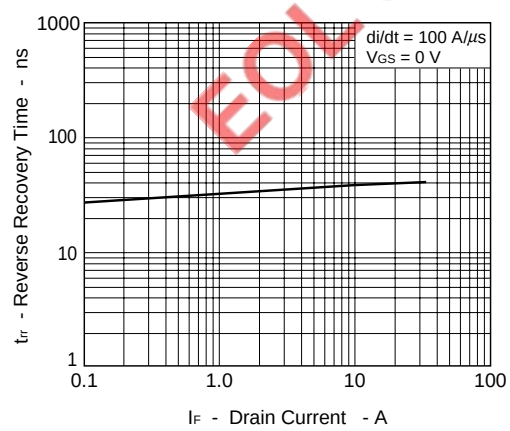
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



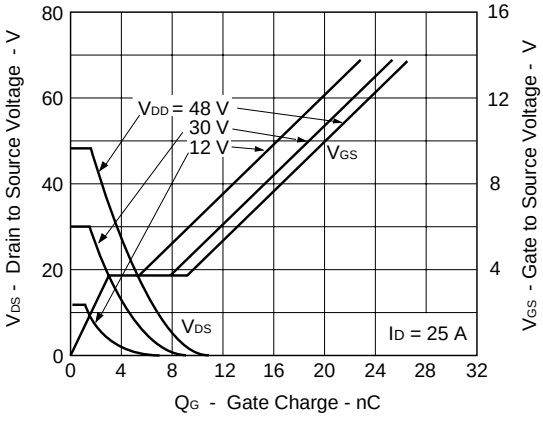
SWITCHING CHARACTERISTICS



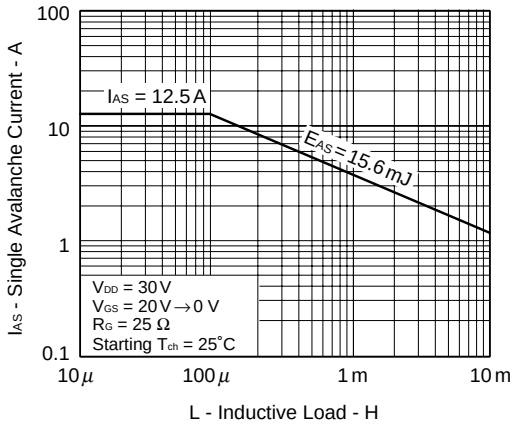
REVERSE RECOVERY TIME vs. DRAIN CURRENT



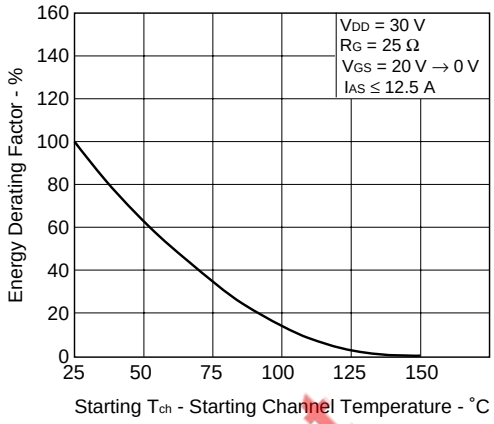
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



★ SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD

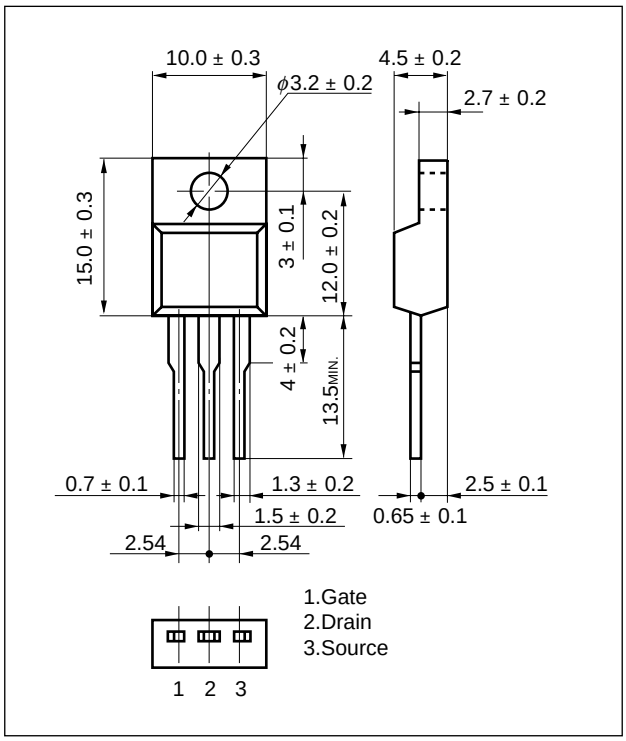


SINGLE AVALANCHE ENERGY DERATING FACTOR

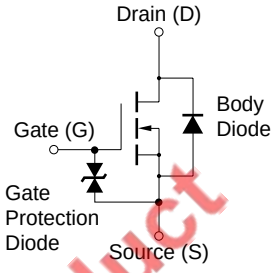


PACKAGE DRAWING

Isolated TO-220 (MP-45F)



EQUIVALENT CIRCUIT



Remark 1. This product is designed for consumer application and isn't suitable for automotive application.

2. The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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